

# 74HC245-Q100; 74HCT245-Q100

Octal bus tranceiver; 3-state

Rev. 1 — 22 July 2013

Product data sheet

## 1. General description

The 74HC245-Q100; 74HCT245-Q100 is an 8-bit transceiver with 3-state outputs. The device features an output enable ( $\overline{OE}$ ) and send/receive (DIR) for direction control. A HIGH on  $\overline{OE}$  causes the outputs to assume a high-impedance OFF-state. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  and from  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$
- Octal bidirectional bus interface
- Non-inverting 3-state outputs
- Multiple package options
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V ( $C = 200 \text{ pF}$ ,  $R = 0 \Omega$ )

## 3. Ordering information

Table 1. Ordering information

Type number	Package				Version
	Temperature range	Name	Description		
74HC245D-Q100	$-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	SO20	plastic small outline package; 20 leads; body width 7.5 mm		SOT163-1
74HCT245D-Q100					
74HC245PW-Q100	$-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm		SOT360-1
74HCT245PW-Q100					
74HC245BQ-Q100	$-40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	DHVQFN20	plastic dual-in-line compatible thermal enhanced very thin quad flat package no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85 \text{ mm}$		SOT764-1
74HCT245BQ-Q100					



#### 4. Functional diagram

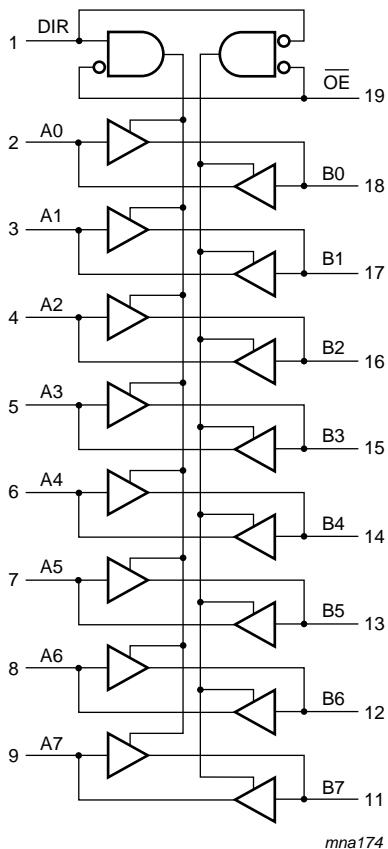


Fig 1. Logic symbol

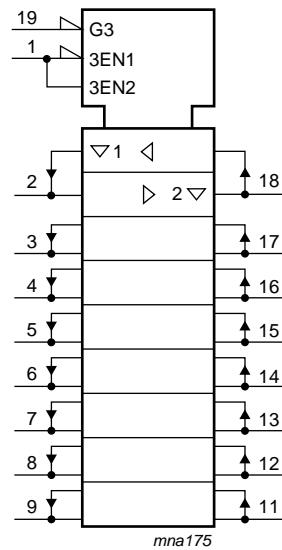


Fig 2. IEC logic symbol

## 5. Pinning information

### 5.1 Pinning

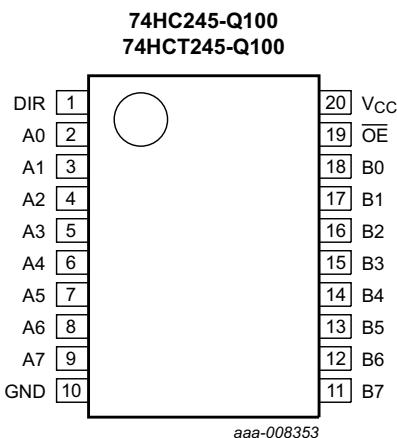
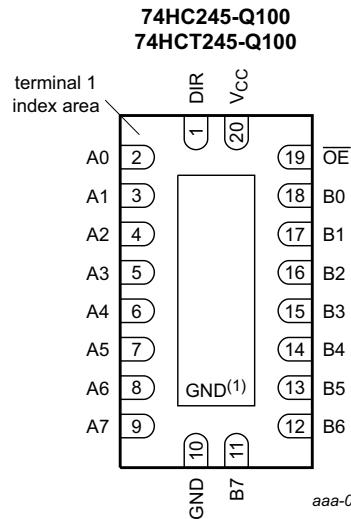


Fig 3. Pin configuration SO20 and TSSOP20



(1) This is not a supply pin. The substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad. However, if it is soldered, the solder land should remain floating or be connected to GND.

Fig 4. Pin configuration DHVQFN20

### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
DIR	1	direction control
A0, A1, A2, A3, A4, A5, A6, A7	2, 3, 4, 5, 6, 7, 8, 9	data input/output
GND	10	ground (0 V)
B0, B1, B2, B3, B4, B5, B6, B7	18, 17, 16, 15, 14, 13, 12, 11	data input/output
OE	19	output enable input (active LOW)
V <sub>CC</sub>	20	supply voltage

## 6. Functional description

Table 3. Function table<sup>[1]</sup>

Input		Input/output	
OE	DIR	An	Bn
L	L	A = B	input
L	H	input	B = A
H	X	Z	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V	-	±20	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V	-	±20	mA
I <sub>O</sub>	output current	V <sub>O</sub> = -0.5 V to V <sub>CC</sub> + 0.5 V	-	±35	mA
I <sub>CC</sub>	supply current		-	+70	mA
I <sub>GND</sub>	ground current		-70	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO20, TSSOP20 and DHVQFN20 packages	<sup>[1]</sup> -	500	mW

[1] For SO20 package: above 70 °C, P<sub>tot</sub> derates linearly with 8 mW/K.

For TSSOP20 package: above 60 °C, P<sub>tot</sub> derates linearly with 5.5 mW/K.

For DHVQFN20 package: above 60 °C, P<sub>tot</sub> derates linearly with 4.5 mW/K.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC245-Q100			74HCT245-Q100			Unit
			Min	Typ	Max	Min	Typ	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

## 9. Static characteristics

**Table 6. Static characteristics type 74HC245-Q100**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 2.0 V	-	0	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 4.5 V	-	0	0.1	V
		I <sub>O</sub> = 20 µA; V <sub>CC</sub> = 6.0 V	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	V
I <sub>I</sub>	input leakage current	I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	V
		V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±0.1	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±0.5	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	8.0	µA
C <sub>I</sub>	input capacitance		-	3.5	-	pF
C <sub>I/O</sub>	input/output capacitance		-	10	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 µA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.34	-	-	V

Table 6. Static characteristics type 74HC245-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	$\pm$ 1.0	$\mu$ A
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	$\pm$ 5.0	$\mu$ A
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	80	$\mu$ A
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		-		
		I <sub>O</sub> = -20 $\mu$ A; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 $\mu$ A; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 $\mu$ A; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		-		
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 $\mu$ A; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.4	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	$\pm$ 1.0	$\mu$ A
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	$\pm$ 10.0	$\mu$ A
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	160	$\mu$ A

Table 7. Static characteristics type 74HCT245-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = -20 µA	4.4	4.5	-	V
		I <sub>O</sub> = -6 mA	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = 20 µA	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA	-	0.15	0.26	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±0.1	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±0.5	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	8.0	µA
ΔI <sub>CC</sub>	additional supply current	per input pin; V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; other inputs at V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A				
		An or Bn inputs	-	40	144	µA
		OE input	-	150	540	µA
		DIR input	-	90	324	µA
C <sub>I</sub>	input capacitance		-	3.5	-	pF
C <sub>I/O</sub>	input/output capacitance		-	10	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = -20 µA	4.4	-	-	V
		I <sub>O</sub> = -6 mA	3.84	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = 20 µA	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA	-	-	0.33	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±1.0	µA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±5.0	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	80	µA

Table 7. Static characteristics type 74HCT245-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\Delta I_{CC}$	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A				
		An or Bn inputs	-	-	180	$\mu$ A
		$\overline{OE}$ input	-	-	675	$\mu$ A
		DIR input	-	-	405	$\mu$ A
<b><math>T_{amb} = -40</math> °C to +125 °C</b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5$ V to 5.5 V	-	-	0.8	V
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5$ V				
		$I_O = -20$ $\mu$ A	4.4	-	-	V
		$I_O = -6$ mA	3.7	-	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5$ V				
		$I_O = 20$ $\mu$ A	-	-	0.1	V
		$I_O = 6.0$ mA	-	-	0.4	V
$I_I$	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V	-	-	$\pm 1.0$	$\mu$ A
$I_{OZ}$	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at $V_{CC}$ or GND; $I_O = 0$ A	-	-	$\pm 10$	$\mu$ A
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	$\mu$ A
$\Delta I_{CC}$	additional supply current	per input pin; $V_I = V_{CC} - 2.1$ V; other inputs at $V_I = V_{CC}$ or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A				
		An or Bn inputs	-	-	196	$\mu$ A
		$\overline{OE}$ input	-	-	735	$\mu$ A
		DIR input	-	-	441	$\mu$ A

## 10. Dynamic characteristics

**Table 8. Dynamic characteristics type 74HC245-Q100**

GND = 0 V; for test circuit, see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>T<sub>amb</sub> = 25 °C</b>							
t <sub>pd</sub>	propagation delay	An to Bn or Bn to An; see <a href="#">Figure 5</a>	[1]				
		V <sub>CC</sub> = 2.0 V	-	25	90	ns	
		V <sub>CC</sub> = 4.5 V	-	9	18	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	7	-	ns	
		V <sub>CC</sub> = 6.0 V	-	7	15	ns	
t <sub>en</sub>	enable time	OE to An or OE to Bn; see <a href="#">Figure 6</a>	[2]				
		V <sub>CC</sub> = 2.0 V	-	30	150	ns	
		V <sub>CC</sub> = 4.5 V	-	11	30	ns	
		V <sub>CC</sub> = 6.0 V	-	9	26	ns	
t <sub>dis</sub>	disable time	OE to An or OE to Bn; see <a href="#">Figure 6</a>	[3]				
		V <sub>CC</sub> = 2.0 V	-	41	150	ns	
		V <sub>CC</sub> = 4.5 V	-	15	30	ns	
		V <sub>CC</sub> = 6.0 V	-	12	26	ns	
t <sub>t</sub>	transition time	An, Bn; see <a href="#">Figure 5</a>	[4]				
		V <sub>CC</sub> = 2.0 V	-	14	60	ns	
		V <sub>CC</sub> = 4.5 V	-	5	12	ns	
		V <sub>CC</sub> = 6.0 V	-	4	10	ns	
C <sub>PD</sub>	power dissipation capacitance	V <sub>I</sub> = GND to V <sub>CC</sub>	[5]	-	30	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>							
t <sub>pd</sub>	propagation delay	An to Bn or Bn to An; see <a href="#">Figure 5</a>	[1]				
		V <sub>CC</sub> = 2.0 V	-	-	115	ns	
		V <sub>CC</sub> = 4.5 V	-	-	23	ns	
		V <sub>CC</sub> = 6.0 V	-	-	20	ns	
t <sub>en</sub>	enable time	OE to An or OE to Bn; see <a href="#">Figure 6</a>	[2]				
		V <sub>CC</sub> = 2.0 V	-	-	190	ns	
		V <sub>CC</sub> = 4.5 V	-	-	38	ns	
		V <sub>CC</sub> = 6.0 V	-	-	33	ns	
t <sub>dis</sub>	disable time	OE to An or OE to Bn; see <a href="#">Figure 6</a>	[3]				
		V <sub>CC</sub> = 2.0 V	-	-	190	ns	
		V <sub>CC</sub> = 4.5 V	-	-	38	ns	
		V <sub>CC</sub> = 6.0 V	-	-	33	ns	

**Table 8. Dynamic characteristics type 74HC245-Q100 ...continued**  
GND = 0 V; for test circuit, see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_t$	transition time	An, Bn; see <a href="#">Figure 5</a>	[4]			
		$V_{CC} = 2.0$ V	-	-	75	ns
		$V_{CC} = 4.5$ V	-	-	15	ns
		$V_{CC} = 6.0$ V	-	-	13	ns
<b><math>T_{amb} = -40</math> °C to +125 °C</b>						
$t_{pd}$	propagation delay	An to Bn or Bn to An; see <a href="#">Figure 5</a>	[1]			
		$V_{CC} = 2.0$ V	-	-	135	ns
		$V_{CC} = 4.5$ V	-	-	27	ns
		$V_{CC} = 6.0$ V	-	-	23	ns
$t_{en}$	enable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; see <a href="#">Figure 6</a>	[2]			
		$V_{CC} = 2.0$ V	-	-	225	ns
		$V_{CC} = 4.5$ V	-	-	45	ns
		$V_{CC} = 6.0$ V	-	-	38	ns
$t_{dis}$	disable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; see <a href="#">Figure 6</a>	[3]			
		$V_{CC} = 2.0$ V	-	-	225	ns
		$V_{CC} = 4.5$ V	-	-	45	ns
		$V_{CC} = 6.0$ V	-	-	38	ns
$t_t$	transition time	An, Bn; see <a href="#">Figure 5</a>	[4]			
		$V_{CC} = 2.0$ V	-	-	90	ns
		$V_{CC} = 4.5$ V	-	-	18	ns
		$V_{CC} = 6.0$ V	-	-	15	ns

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[3]  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[4]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

N = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

Table 9. Dynamic characteristics type 74HCT245-Q100

GND = 0 V; for test circuit, see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>T<sub>amb</sub> = 25 °C</b>							
t <sub>pd</sub>	propagation delay	An to Bn or Bn to An; see <a href="#">Figure 5</a>	[1]				
		V <sub>CC</sub> = 4.5 V	-	12	22	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	10	-	ns	
t <sub>en</sub>	enable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 6</a>	[2]	-	16	30	ns
t <sub>dis</sub>	disable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 6</a>	[3]	-	16	30	ns
t <sub>t</sub>	transition time	An, Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 5</a>	[4]	-	5	12	ns
C <sub>PD</sub>	power dissipation capacitance	V <sub>I</sub> = GND to V <sub>CC</sub> – 1.5 V	[5]	-	30	-	pF
<b>T<sub>amb</sub> = –40 °C to +85 °C</b>							
t <sub>pd</sub>	propagation delay	V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 5</a>	[1]	-	-	28	ns
t <sub>en</sub>	enable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 6</a>	[2]	-	-	38	ns
t <sub>dis</sub>	disable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 6</a>	[3]	-	-	38	ns
t <sub>t</sub>	transition time	An, Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 5</a>	[4]	-	-	15	ns
<b>T<sub>amb</sub> = –40 °C to +125 °C</b>							
t <sub>pd</sub>	propagation delay	V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 5</a>	[1]	-	-	33	ns
t <sub>en</sub>	enable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 6</a>	[2]	-	-	45	ns
t <sub>dis</sub>	disable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 6</a>	[3]	-	-	45	ns
t <sub>t</sub>	transition time	An, Bn; V <sub>CC</sub> = 4.5 V; see <a href="#">Figure 5</a>	[4]	-	-	18	ns

[1] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.[2] t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.[3] t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub>.[4] t<sub>t</sub> is the same as t<sub>THL</sub> and t<sub>TLH</sub>.[5] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

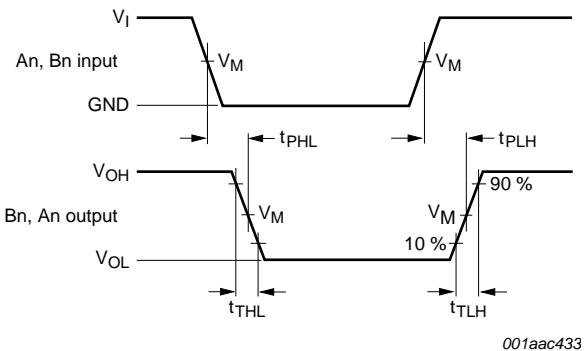
$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz;f<sub>o</sub> = output frequency in MHz;C<sub>L</sub> = output load capacitance in pF;V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

$$\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$$

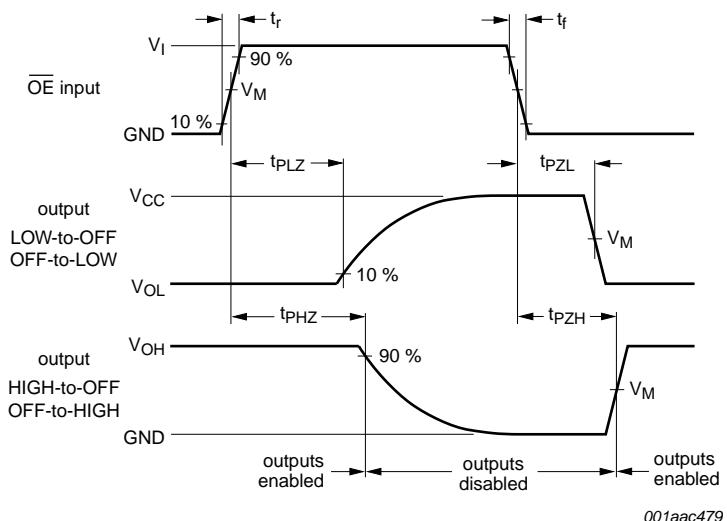
## 11. Waveforms



Measurement points are given in [Table 10](#).

$V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 5. Input (An, Bn) to output (Bn, An) propagation delays and output transition times**



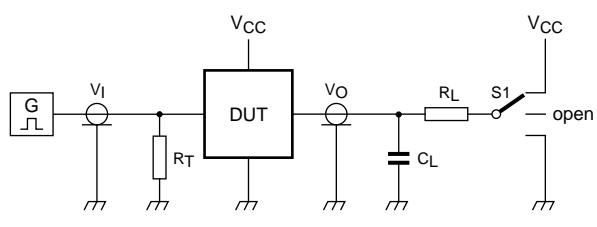
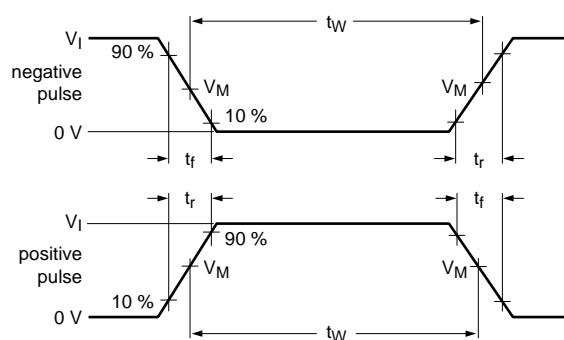
Measurement points are given in [Table 10](#).

$V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 6. 3-state output enable and disable times**

**Table 10. Measurement points**

Type	Input	Output
	$V_M$	$V_M$
74HC245-Q100	$0.5V_{CC}$	$0.5V_{CC}$
74HCT245-Q100	1.3 V	1.3 V



Test data is given in [Table 11](#).

Definitions test circuit:

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_L$  = Load resistance.

$S1$  = Test selection switch.

**Fig 7. Test circuit for measuring switching times**

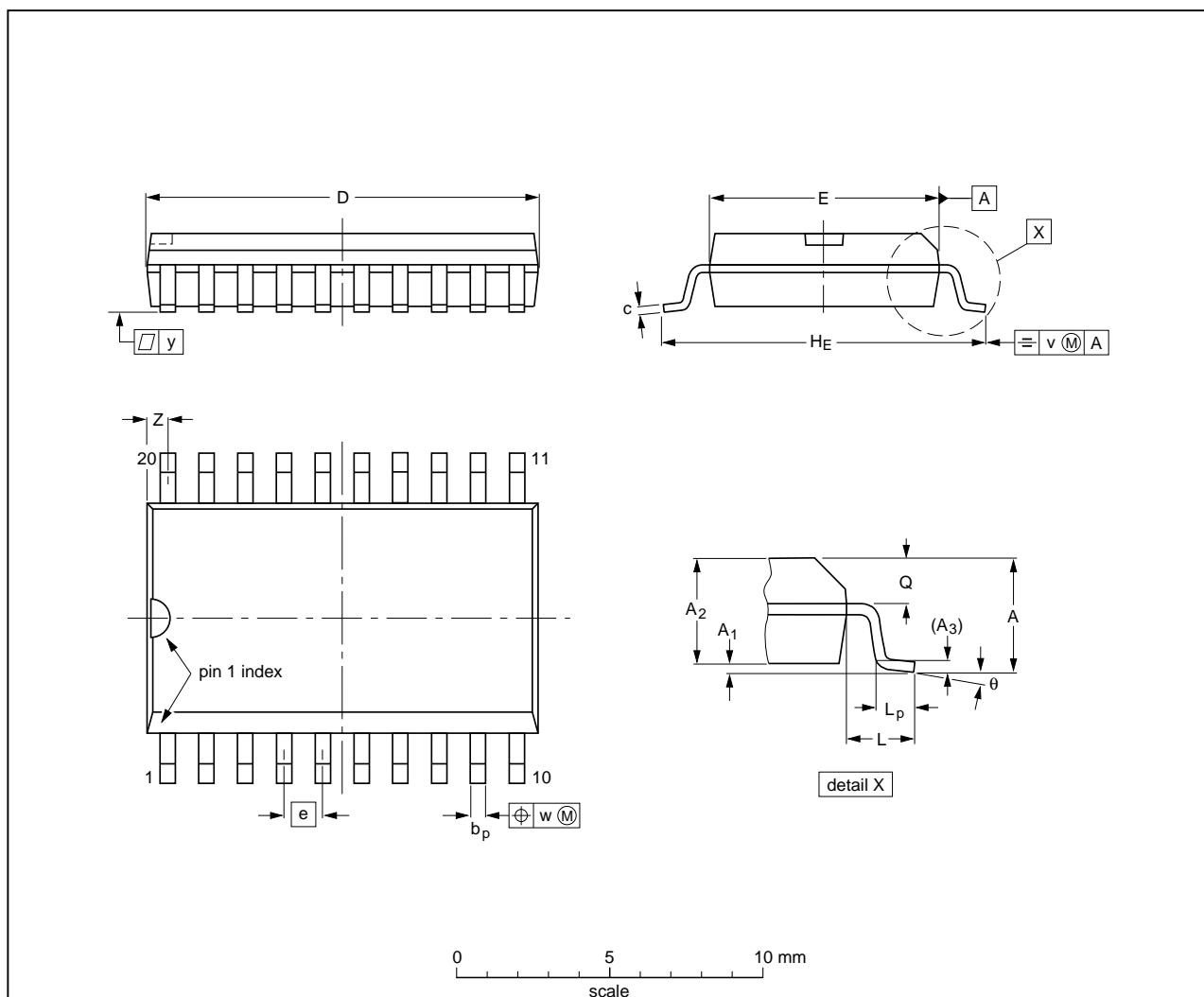
**Table 11. Test data**

Type	Input		Load		S1 position		
	$V_I$	$t_r, t_f$	$C_L$	$R_L$	$t_{PHL}, t_{PLH}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$
74HC245-Q100	$V_{CC}$	6 ns	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$
74HCT245-Q100	3 V	6 ns	15 pF, 50 pF	1 k $\Omega$	open	GND	$V_{CC}$

## 12. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	H <sub>E</sub>	L	L <sub>p</sub>	Q	v	w	y	z <sup>(1)</sup>	θ
mm	2.65 0.1	0.3 2.25	2.45	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT163-1	075E04	MS-013				09-12-27 03-02-19

Fig 8. Package outline SOT163-1 (SO20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

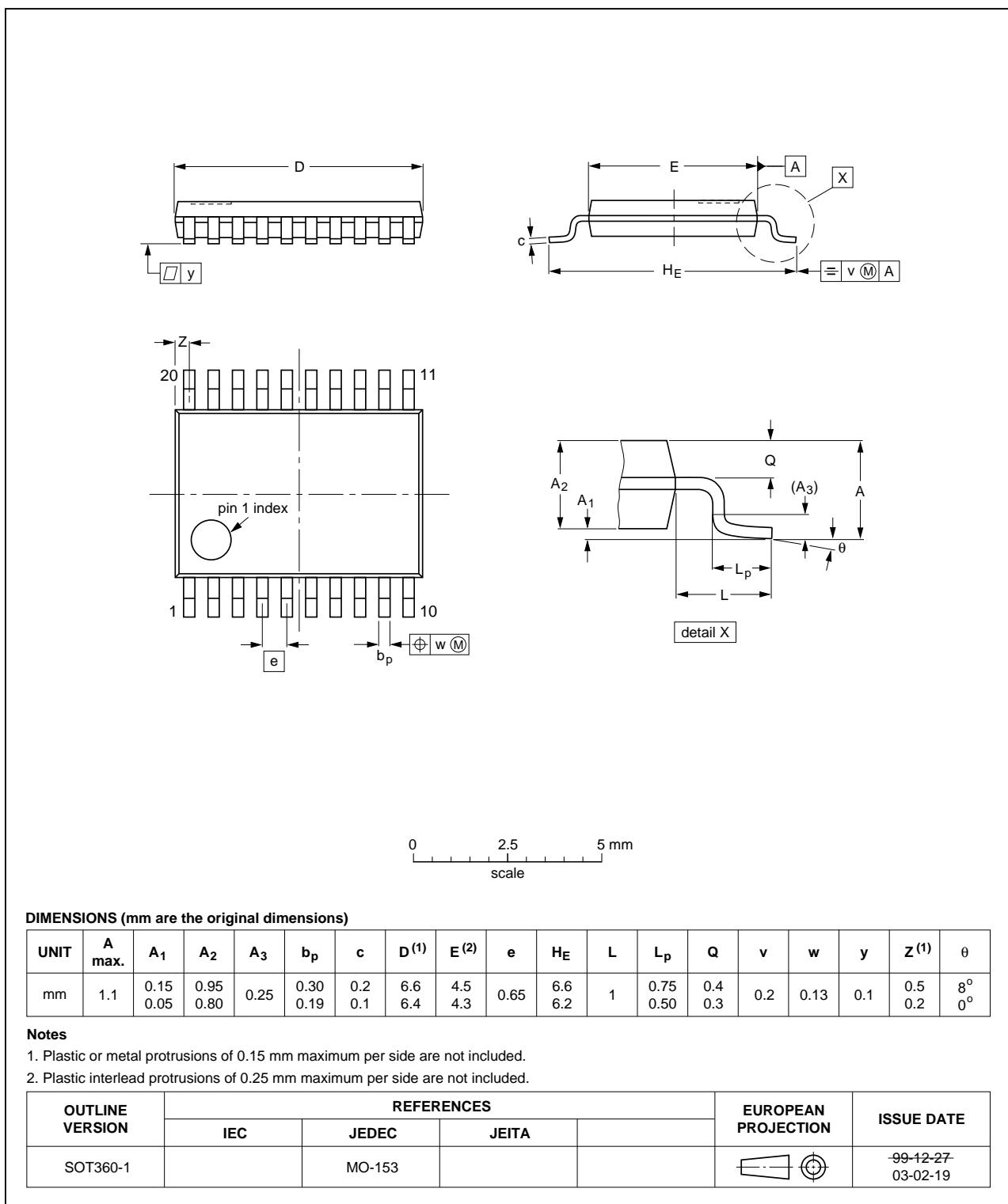


Fig 9. Package outline SOT360-1 (TSSOP20)

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;  
20 terminals; body 2.5 x 4.5 x 0.85 mm

SOT764-1

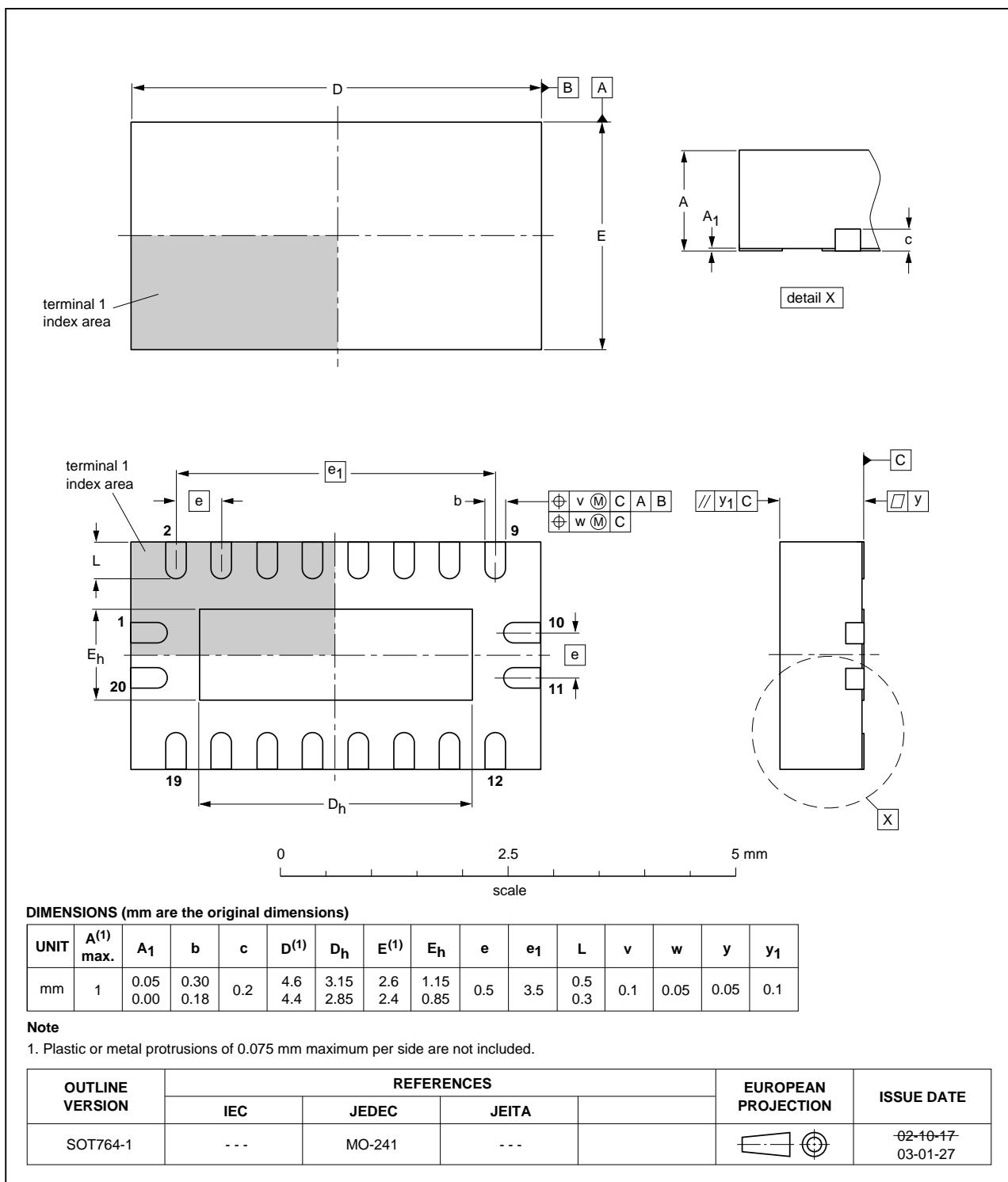


Fig 10. Package outline SOT764-1 (DHVQFN20)

## 13. Abbreviations

**Table 12. Abbreviations**

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
MIL	Military

## 14. Revision history

**Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT245_Q100 v.1	20130722	Product data sheet	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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